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2015 New J. Phys. 17 113042
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Magnetism-induced massive Dirac spectra and topological defects in the surface state of Cr-doped Bi$_2$Se$_3$-bilayer topological insulators

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Keywords: topological insulators, surface state, Dirac fermions, scanning tunneling spectroscopy, proximity effect, ferromagnetism, impurity resonances

Supplementary material for this article is available online

Abstract

Proximity-induced magnetic effects on the surface Dirac spectra of topological insulators are investigated by scanning tunneling spectroscopic studies of bilayer structures consisting of undoped Bi$_2$Se$_3$ thin films on top of Cr-doped Bi$_2$Se$_3$ layers. For thickness of the top Bi$_2$Se$_3$ layer equal to or smaller than 3 quintuple layers, a spatially inhomogeneous surface spectral gap $\Delta$ opens up below a characteristic temperature $T_c$\textsubscript{2D}, which is much higher than the bulk Curie temperature $T_c$\textsubscript{3D} determined from the anomalous Hall resistance. The mean value and spatial homogeneity of the gap $\Delta$ generally increase with increasing c-axis magnetic field ($H$) and increasing Cr doping level ($x$), suggesting that the physical origin of this surface gap is associated with proximity-induced c-axis ferromagnetism. On the other hand, the temperature ($T$) dependence of $\Delta$ is non-monotonic, showing initial increase below $T_c$\textsubscript{2D}, which is followed by a ‘dip’ and then rises again, reaching maximum at $T \ll T_c$\textsubscript{3D}. These phenomena may be attributed to proximity magnetism induced by two types of contributions with different temperature dependences: a three-dimensional contribution from the bulk magnetism that dominates at low $T$, and a two-dimensional contribution associated with the RKKY interactions mediated by surface Dirac fermions, which dominates at $T_c$\textsubscript{2D} $< T < T_c$\textsubscript{3D}. In addition to the observed proximity magnetism, spatially localized sharp resonant spectra are found along the boundaries of gapped and gapless regions. These spectral resonances are long-lived at $H = 0$, with their occurrences being most prominent near $T_c$\textsubscript{2D} and becoming suppressed under strong c-axis magnetic fields. We attribute these phenomena to magnetic impurity-induced topological defects in the spin texture of surface Dirac fermions, with the magnetic impurities being isolated Cr impurities distributed near the interface of the bilayer system. The long-term stability of these topologically protected two-level states may find potential applications to quantum information technology.

1. Introduction

The research of topological matter is an exciting frontier where the classification of quantum states of matter beyond the principle of symmetry breaking has stimulated many conceptual advances and experimental discoveries [1–3]. Among various topological matter, topological insulators (TIs) [4–8] are bulk insulators in two or three dimensions with strong spin–orbit coupling and gapless surface states protected by the time-reversal invariance. The gapless surface state of TIs consists of an odd number of Dirac cones where the energy-momentum dispersion relation is linear, similar to the massless Dirac fermions in graphene except for the odd number of Dirac cones and an additional spin–momentum locking in the former. Gapping the Dirac cones of TIs by introducing superconductivity [9–11] or magnetism [8, 9, 12, 13] via either doping or proximity effects
can provide feasible means to realize the elusive Majorana modes [9, 10, 14] and topological magnetoelectric effect [12, 13] in condensed matter systems.

The underlying physics for a magnetism-induced surface gap in three-dimensional (3D) TIs is based on the assumption that the long-range ferromagnetism has a net magnetization $M$ perpendicular to the surface of the 3D-TI, and that the in-plane component of the Hamiltonian $H_0$ for the surface Dirac fermions remains intact after the introduction of c-axis magnetization. Hence, the total Hamiltonian $H_{\text{total}}$ for the Dirac fermions becomes

$$H_{\text{total}} = H_0 + \frac{1}{2} J_{\text{eff}} M \sigma_z \equiv \hbar v_F \left( k_x \sigma_y - k_y \sigma_x \right) + \frac{1}{2} J_{\text{eff}} M \sigma_z,$$

(1)

where $\sigma_{x,y,z}$ are the Pauli matrices, $k_{x,y}$ refer to the in-plane momentum of the Dirac fermions, $J_{\text{eff}}$ denotes the ferromagnetic coupling constant in the surface state, and $v_F$ is the Fermi velocity. The energy dispersion relation $E^\pm_k$ for the magnetism-induced massive Dirac fermions can be obtained by diagonalizing $H_{\text{total}}$ in equation (1), which yields

$$E^\pm_k = \pm \sqrt{\left(v_F k\right)^2 + \left(J_{\text{eff}} M / 2\right)^2},$$

(2)

where $k^2 \equiv k_x^2 + k_y^2.$ Hence, an energy gap $\Delta = (J_{\text{eff}} M)$ opens up at the Dirac point for a finite c-axis magnetization $|M| > 0$ according to equation (2).

Experimental evidences for the occurrence of long-range ferromagnetism in the surface state of 3D-TIs have been manifested by the observation of surface gap opening in angle resolved photoemission spectroscopy (ARPES) [15–18] and the confirmation of quantized anomalous Hall effect [19, 20] in magnetic 3D-TIs (Bi$_1$$_x$Cr$_{x}$)$_2$Te$_3$. However, the microscopic mechanism that mediates long-range ferromagnetism in the surface state has not been fully established [18, 21–26]. A number of puzzling phenomena, such as a surface gap opening at a temperature $T_c^{2D}$ much higher than the onset temperature of bulk magnetization $T_c^{3D}$ [15–17, 22–25], the absence of gap formation by direct surface magnetic doping [27], and the lack of direct scanning tunneling spectroscopic (STS) evidence for either magnetism-induced surface gaps [30] or spectroscopic magnetic impurity resonances [21], all suggest that further investigation is needed.

We report in this work direct evidence for magnetism-induced surface state energy gaps and magnetic impurity resonances in 3D-TIs by STS studies of bilayer structures of Bi$_2$Se$_3$ and Cr-doped Bi$_2$Se$_3$. The bilayer samples were grown by molecular beam epitaxy (MBE) on InP (111) single crystalline substrates, with an undoped Bi$_2$Se$_3$ layer of varying thicknesses, $d_1$, quintuple layers (QLs), on top of a Cr-doped Bi$_2$Se$_3$ layer of a fixed thickness $d_2 = 6$-QL. These bilayer structures ensured that magnetism may be observed in the undoped Bi$_2$Se$_3$ through the proximity effect for sufficiently small $d_1$ values, which prevented possible complications due to Cr-doping induced changes in the electronic bandstructures of Bi$_2$Se$_3$, and thus enabled direct observation of the effect of global time-reversal symmetry breaking on the surface state of TIs. Finally, we discuss the implications of our findings on applications of magnetically doped TIs to spintronics and quantum information technology.

2. Methods

The samples investigated in this work consisted of MBE-grown bilayer structures as schematically shown in figure 1(a), where $d_1 = 1, 3, 5, 7$-QL for the 10% Cr-doping level, and $d_1 = 1$-QL for 5% Cr-doping. Hereafter we use the nomenclature $(d_1 + d_2)$-x% to denote our samples. Details of the growth process, structural characterizations and ARPES studies of these bilayer samples have been reported elsewhere [18, 28, 29]. Bulk electrical transport measurements on these samples revealed the appearance of anomalous Hall resistance at $T \leq T_c^{3D},$ where $T_c^{3D} \sim 30$ K and 20 K for $x = 10\%$ and 5%, respectively, as exemplified in figure 1(b).

Additionally, surface magneto-optic Kerr effect measurements have been performed on similar bilayer samples, showing finite Kerr angles $\theta_k$ at $T < T_c^{3D},$ with temperature and magnetic field dependence similar to those of the anomalous Hall resistance [18], as exemplified in supplementary figures 1(a)–(c).

For the STM studies, each bilayer sample was capped with $\sim$1 nm Se inside the MBE growth chamber for passivation immediately after the bilayer growth. The sample was subsequently transferred from the growth chamber via a vacuum suitcase to another vacuum chamber, where the sample was annealed at 423 K $\sim$ 473 K for 90 min under vacuum ($<10^{-5}$ Torr) to remove the Se capping layer. The exposed bilayer sample was cooled to 300 K in vacuum, and then the sample-containing chamber was filled with Ar gas and loaded into an Ar-filled glove box, where the sample was removed from the chamber and transferred to the STM probe placed in the same glove box. The STM probe was sealed, transferred to its cryostat, and then evacuated down to $\sim$10$^{-10}$ Torr at liquid helium temperatures. The variable temperature range achievable for our homemade STM system was from 300 K to $\sim$ 10 K, and a superconducting magnet was available to provide magnetic fields up to $\sim$7 Tesla.
3. Results and analysis

In this work both topographic and spectroscopic studies were made on all samples as a function of $T$ (from 300 K to 15 K) and $H$ (from 0 to 3.5 Tesla) using the variable temperature STM.

3.1. Structural characteristics from surface topographic studies

The surface topography on large scales revealed pyramid-like terraces with steps corresponding to single atomic layers, as described previously [28, 29]. For an averaged, nominal top layer thickness $d_1$-QL, the local thickness of the top layer could vary up to 1-QL. Atomically resolved topographic images exhibited triangular lattice patterns that were always consistent with that of pure Bi$_2$Se$_3$, as exemplified in figure 2(a) and figure 2(b) for $(1 + 6)$-10% and $(5 + 6)$-10% samples, respectively. On the other hand, the Fourier transformation (FT) of the surface topography appeared to be dependent on $d_1$. We found that FT of the $(1 + 6)$-10% topography showed an expected hexagonal Bragg diffraction pattern for Bi$_2$Se$_3$ plus an additional, faint superlattice structure (figure 2(c)), which may be attributed to the underlying Cr-doped Bi$_2$Se$_3$. For instance, a periodic substitution of Cr for Bi as exemplified in figure 2(f) for a two-dimensional projection of the two Bi-layers within one-QL yields a FT pattern (figure 2(e)) similar to that in figure 2(c). This superlattice structure corresponds to a local Cr concentration of 1/12. Another similar structure with a local Cr concentration of 1/8 (figure 2(h)) is also feasible within experimental uncertainties of the superlattice constant and its angle relative to the Bi lattice (figure 2(g)).

In contrast, the FT in figure 2(d) for the surface topography of a $(5 + 6)$-10% sample only revealed the hexagonal diffraction pattern of pure Bi$_2$Se$_3$ due to the relatively thick $d_1$ layer. Interestingly, we note that the FT topography of the $(1 + 6)$-5% samples also agreed with figure 2(d), suggesting random Cr substitutions of Bi for a smaller Cr concentration, which is consistent with the randomly distributed Cr clusters found with STM studies directly on 2% Cr-doped Bi$_2$Se$_3$ [30].

3.2. Zero-field spectroscopic studies

For the zero-field studies, tunneling conductance ($dI/dV$) versus biased voltage ($V = E/e$) measurements were carried out on each sample over multiple areas, followed by detailed analysis of the spatially resolved spectral characteristics. While apparent spatial variations were found in all samples, systematic investigations led to several general findings. First, all samples revealed gapless Dirac tunneling spectra at 300 K. Second, with decreasing $T$ there were two distinctly different types of spectral characteristics: For samples with nominal $d_1 = 5$ and 7, the tunneling spectra remained gapless for all $T$, except for occasional areas where the actual $d_1$ values in the nominal $d_1 = 5$ sample were $\sim 4$. In contrast, for samples with nominal $d_1 = 1$ and 3, the majority spectra revealed gapped features at $T < T_c^{3D}$, and the temperature evolution for all samples are exemplified in figures 3(a)–(d). Third, the surface gap $\Delta (r, T)$, obtained by the spectral analysis illustrated in figure 3(e), appeared to be spatially inhomogeneous where $r$ denotes the two-dimensional spatial coordinate.

For a given $r$, $\Delta$ mostly increased with decreasing $T$ except near $T_x \sim (110 \pm 10)$ K where a slight dip appeared, and eventually saturated to a maximum value at $T < T_c^{3D} < T_c^{1D}$, as exemplified by the $T$ evolution of the gap maps and the corresponding gap histograms in the left and middle panels of figures 4(a)–(c) for the
(1 + 6)-5%, (1 + 6)-10% and (3 + 6)-10% samples, and also summarized in the right panels for the temperature dependence of the corresponding mean gap $\Delta(T)$. Here the mean gap value $\Delta$ at a given $T$ was determined from the peak value of Gaussian fitting to the gap histogram, and the errors were determined from the one sigma linewidth of the Gaussian fitting. Based on the data for $\Delta(T)$, the onset $T_c$ for the surface gap opening was found to be $T_c^{2D} = (240 \pm 10)$ K for $x = 10\%$ and $T_c^{2D} = (210 \pm 10)$ K for $x = 5\%$, significantly higher than the bulk Curie temperatures $T_C^{3D}$ = 30 ~ 20 K obtained from the onset temperature of the anomalous Hall resistance. This finding of $T_c^{2D} \gg T_c^{3D}$ is in fact consistent with previous reports on other families of 3D-TIs [15-17]. As we shall elaborate further in Discussion, the non-monotonic temperature dependence of the surface gap and the relation of $T_c^{2D} \gg T_c^{3D}$ may be the result of multiple magnetic interaction components in the bilayer samples, with each component having a different temperature dependence and interaction range.

The inhomogeneous gap distribution may be attributed to multiple reasons. First, the Cr-substitution of Bi may not be uniform due to the size mismatch, which could induce lattice strain and inhomogeneous ferromagnetism. Second, the magnetic moments of Cr ions may not be well aligned along the sample $c$-axis without an external magnetic field. Given that only $c$-axis magnetization component can induce a surface gap in 3D-TIs according to equations (1) and (2), varying spin alignments in different magnetic domains would result in varying surface gaps [31]. Third, the sample surface exhibited terrace structures with $\sim 1$-QL thickness variations [28], which could give rise to varying proximity-induced gaps from the RKKY interaction mediated by surface Dirac fermions [18, 22-24].

To better understand how the aforementioned components contribute to the gap inhomogeneity, we compare the surface topography of the bilayer samples with their corresponding gap maps. As exemplified in supplementary figures 2(a)-(b) and discussed further in the supplementary information, we find that the correlation between a typical surface topography map and the corresponding gap map over the same area of a bilayer sample is finite although relatively weak. The weak correlation is primarily due to small height variations over the typical areas of our STM studies. Thus, the primary cause of spatially inhomogeneous gaps in the bilayer systems may be attributed to inhomogeneous Cr distributions and the misalignment of Cr magnetic moments. Experimentally, the latter effect may be minimized by applying a strong external magnetic field along the $c$-axis, which is the subject of our investigation in the next subsection.

Figure 2. Structural characteristics of MBE-grown Bi$_2$Se$_3$ bilayer samples on InP (111): (a) surface topography of a (1 + 6)-10% sample over an area of $(6 \times 6)$ nm$^2$, showing a triangular lattice structure. (b) Surface topography of a (5 + 6)-10% sample over an area of $(6 \times 6)$ nm$^2$, showing a triangular lattice. (c) Fourier transformation (FT) of the surface topography in a (1 + 6)-10% sample, revealing a dominant hexagonal reciprocal lattice structure and a secondary superlattice of a much weaker intensity, probably coming from the underlying Cr-doped Bi$_2$Se$_3$ layer. Here ‘a’ in the reciprocal space scale $(2\pi/a\sqrt{3})$ refers to the in-plane nearest neighbor distance between Bi (Se) and Bi (Se). (d) FT of the surface topography on a (5 + 6)-10% sample, showing a purely hexagonal reciprocal lattice. (e) Simulated FT of the 1/12 Cr-substituted Bi layer illustrated in (f), showing a FT similar the data in (c). Here the blue dots represent Bi atoms and the red dots represent Cr substitutions. (g) Simulated FT of the 1/8 Cr-substituted Bi layer illustrated in (h), showing a FT also similar the data in (c) within experimental errors.
saturating the bulk ferromagnetism

3.3. Finite-field spectroscopic studies

We further investigated the effect of increasing c-axis magnetic field \( H \) on the gap distribution over the same area of each sample at a constant \( T \). As exemplified in figure 5(a)–(f) for samples of \((1 + 6)\)-5\% and \((3 + 6)\)-10\% taken at \( T = 18 \) K and \( H = 0, 1.5 \) T and \( 3.5 \) T, the gap maps became increasingly homogeneous and the mean gap value \( \Delta \) derived from the histogram also increased slightly with increasing \( H \). This finding suggests that the observed surface gap is consistent with c-axis ferromagnetism induced by Cr-doping and proximity effect, and the characteristic field for saturating the surface state ferromagnetism appears to be larger than that for saturating the bulk ferromagnetism [18], probably due to the helical spin textures of the former. The small but finite residual gap inhomogeneity in high fields may be primarily attributed to spatially inhomogeneous Cr-distributions.

3.4. Minority spectra

While the majority of the tunneling spectra in the \((1 + 6)\)-5\%, \((1 + 6)\)-10\% and \((3 + 6)\)-10\% samples revealed gapped characteristics for \( T < T_c^{2D} \), spatially localized and intense conductance peaks were occasionally observed along the borders of gapless and gapped regions, as exemplified in figures 6(a)–(d) for a \((1 + 6)\)-5\% sample and in figure 6(f) for a \((1 + 6)\)-10\% sample. These long-lived minority spectra either consisted of a single sharp conductance peak at a small negative energy \( E = E_\Delta \) near the Dirac point \( E_D \); or comprised of double conductance peaks (figure 6(b)) at \( E = E_\Delta \), and \( E = E_{\Delta h} \), where \( E_{\Delta h} \) is near the Fermi energy \( E_F = 0 \). These double-peak spectral characteristics were consistent with theoretical predictions for magnetic impurity resonances [25]. Further, the numbers of both single- and double-peak impurity resonances at \( H = 0 \) were found to increase rapidly near \( T_c^{2D} \) (figure 6(f)). In contrast, all resonances disappeared under a large c-axis magnetic field at low \( T \) when gapless regions diminished.

We attribute the sharp impurity resonances to isolated Cr-impurities that were far away from neighboring Cr ions and probably had partially diffused from the \( d_{z^2} \)-layer into the interfacial region, because they were only
found in zero-field along the borders between gapless and gapped regions, and then disappeared under a large c-axis magnetic field when gapless regions diminished and long-range ferromagnetism was established. The strongly non-monotonic temperature dependence of the number of impurity resonances at $H = 0$ (see figure 6(f)) may be understood as the result of weakening surface ferromagnetism near $T_{C^2D}$, so that more Cr-impurities became decoupled and acted like isolated impurities. The strong spatial localization and long lifetime

Figure 4. Temperature evolution and spatial distribution of the surface gap at $H = 0$: (a) gap maps and the corresponding histograms of a $(1+6)$-5% sample taken at $T = 80$ K (left panels) and $T = 164$ K (middle panels), and the $T$-dependence of the mean gap $\Delta$ (second right panel). (b) Gap map and the corresponding histograms of a $(1+6)$-10% sample taken at $T = 79$ K (left panels) and $T = 153$ K (middle panels), and the $T$-dependence of the mean gap $\Delta$ (third right panel). (c) Gap maps and the corresponding histograms of a $(3+6)$-10% sample taken at $T = 20$ K (left panels) and $T = 79$ K (middle panels), and the $T$-dependence of the mean gap $\Delta$ (fourth right panel). The first right panel is a schematic illustration of the spatially varying electronic structure experienced by the tunneling current, showing the dominance of the surface state gap $\Delta$ over the bulk gap $\Delta_B$ in determining the measured spectral gap in STS.
of these magnetic impurity resonances at $H = 0$ may be attributed to topological protection of the surface state in 3D-TIs when the Dirac energy $E_D$ is relatively close to $E_F$, similar to the case for non-magnetic impurities [25, 32].

We further remark that our finding of atomically sharp impurity resonances due to isolated Cr ions differs from direct STM studies of bare 2% Cr-doped Bi$_2$Se$_3$ [30]: in the latter case, direct atomic imaging revealed that Cr substituted Bi in clusters so that the resulting spectroscopy did not behave like isolated magnetic impurities embedded in the surface state of pure Bi$_2$Se$_3$. In contrast, our identification of isolated Cr-impurities in the bilayer systems was solely based on spatially resolved spectroscopic evidences without directly imaging the Cr impurities, because Cr ions could not diffuse all the way to the top surface and were still buried by the undoped Bi$_2$Se$_3$ layer. Therefore, STM imaging of all bilayer samples always revealed the atomic structure of pure Bi$_2$Se$_3$.

Figure 5. Evolution of the surface gap distribution at $T = 18$ K with applied c-axis magnetic field: (a)–(c) gap maps (upper panels) and the corresponding gap histograms (lower panels) of a (1 + 6)-5% sample taken at $H = 0$, 1.5 T and 3.5 T over the same (47 × 47) nm$^2$ area. (d)–(f) Gap maps (upper panels) and the corresponding gap histograms (lower panels) of a (3 + 6)-10% sample taken at $H = 0$, 1.5 T and 3.5 T over the same (24 × 24) nm$^2$ area.
as exemplified in figures 2(a) and (b). Additionally, we have found no evidences for the formation of Cr clusters at the interface of our bilayer samples: The STEM studies of typical bilayer samples revealed atomically sharp interfaces without any cluster-induced variations in the c-axis lattice spacing; our bilayer samples also exhibited well defined 3D ferromagnetism below an appreciable $T_{c\text{ 3D}}$ ($20 \sim 30$ K), which was consistent with more dispersed and uniform distributions of Cr in order to achieve long-range ferromagnetic order. The latter situation was in stark contrast to the absence of long-range ferromagnetism down to 1.5 K in the 2% Cr-doped $\text{Bi}_2\text{Se}_3$ sample that exhibited randomly distributed surface Cr-clusters. In fact, a recent report based on direct STM studies on a similar TI system ($\text{Bi}_{0.1}\text{Sb}_{0.9}1.92\text{Cr}_{0.08}\text{Te}_3$ (with $T_{c\text{ 3D}} \sim 18$ K and 4% Cr-doping))

**Figure 6.** Spectral characteristics of isolated magnetic impurities: (a) gap map of a $(1+6)$-5% bilayer sample taken at 80 K and $H = 0$ over an area of $(13 \times 13)$ nm$^2$, showing both spatially inhomogeneous gaps and some gapless regions (dark blue). The arrow indicates a site where a spatially localized double-resonant spectrum in (b) is observed. (b) Sharp resonances of an isolated impurity are manifested in the $(dI/dV)$ versus $E$ and $X$ plot, where $X$ is a horizontal linecut across an isolated impurity indicated by the arrow in (c). The sharp double resonant peaks appear at $E = E_-$ and $E = E_+$, where $E_-$ is near $E_D$ and $E_+$ is near $E_F$. (c) Tunneling conductance map taken at $E = E_-$ over the same area as in (a), showing spatially isolated conductance peaks in bright sharp spots. (d) Two-dimensional distribution of the tunneling conductance at bias voltage $V = (E_- - E)/e$ over a $(4 \times 4)$ nm$^2$ area indicated by the dashed box in (c), showing three sites with intense impurity resonances. (e) Schematics of a topological defect (red arrows of opposite helicity) due to an isolated magnetic impurity in the surface-state Dirac spin textures (counterclockwise black arrows). (f) $T$-evolution of the counts of single- and double-peak and total impurity resonances over a $(20 \times 20)$ nm$^2$ area of a $(1+6)$-10% sample, showing a rapid increase in the number of impurity resonances near $T_{c\text{ 2D}}$ for both the single- and double-peak resonances.
revealed completely dispersed distributions of Cr and inhomogeneous gaps without evidences for cluster formation\cite{33}. These findings are consistent with what we have inferred from our experimental studies of the (Bi$_{1-x}$Cr$_x$)$_2$Se$_3$/Bi$_2$Se$_3$ bilayer systems.

4. Discussion

In this session we address issues associated with the physical mechanism for proximity magnetism, the physical origin and the magnitude of the surface energy gap, the feasibility of high surface $T_c$ values relative to the bulk $T_c$, and the topological spin textures in the presence of isolated magnetic impurities.

4.1. Proximity magnetism in the bilayer system

Our experimental results have demonstrated that the dependence of the spectral characteristics on $T$, $H$, $x$ and $d_1$ for the bilayer samples are all consistent with the scenario that a surface-state gap was induced by the proximity effect of predominantly $c$-axis ferromagnetism in the Cr-doped bottom layer. The appearance (absence) of gapped tunneling spectra below $T_c$ for bilayer samples with $d_1 \leq 3$-QL ($d_1 \geq 5$-QL) suggests that the proximity effect due to $c$-axis magnetic correlation is limited to a critical thickness $d_c \sim 4$-QL.

In our investigation of the Cr-doped bilayer system, it is important to realize that the undoped Bi$_2$Se$_3$ layer should not be considered as an isolated ultrathin film on a ‘substrate’ of Cr-doped Bi$_2$Se$_3$. This realization is because of the continuous and seamless growth of undoped Bi$_2$Se$_3$ layer on top of the isoststructure, Cr-doped Bi$_2$Se$_3$ layer\cite{18}, leading to an effective total thickness of $(d_1 + d_2)$-QL. In contrast, for ultra-thin TI films on dissimilar substrates, an energy gap can open up due to coupling between the top and bottom topological surface states, and a Rashba-like coupling with further energy splitting in momentum can also be expected due to the asymmetric chemical potentials between the surface of the thin film and its interface with a dissimilar substrate \cite{34}. This Rashba-like coupling has indeed been confirmed by ARPES and STS studies for 2-QL to 5-QL Bi$_2$Se$_3$ on various dissimilar substrates\cite{35,36}. In particular, the energy gap induced by the Rashba-like coupling for ultra-thin TI films on dissimilar substrates does not exhibit any discernible temperature or magnetic field dependence, which is in sharp contrast to the behavior of the proximity-magnetism induced surface gaps described in this work.

Having established proximity magnetism as the physical origin of the surface gap in the bilayer system, we consider next the primary components that contribute to the surface ferromagnetism in the undoped Bi$_2$Se$_3$ layer of $d_1 \leq 3$-QL. A natural component is the dipole field associated with the magnetic moments of Cr ions. Additionally, RKKY-like magnetic interactions mediated by the bulk carriers and the surface Dirac fermions are also feasible contributions to the surface ferromagnetism. Therefore, we may express the effective ferromagnetic coupling constant $J_{\text{eff}}$ in terms of the sum of these three components, $J_{\text{eff}} = (J_{\text{dipole}} + J_{\text{bulk}}) + J_{\text{Dirac}}$, where $(J_{\text{dipole}} + J_{\text{bulk}}) \equiv J_{\text{SD}}$ may be considered as a 3D component and $J_{\text{Dirac}} \equiv J_{\text{2D}}$ a 2D component. We expect $J_{\text{SD}}$ to vary slowly with $d_1$ because it primarily represents the bulk magnetic properties of the Cr-doped Bi$_2$Se$_3$. In contrast, $J_{\text{2D}} \propto \exp(-2d_1/d_2)$ is strongly dependent on $d_1$ because it involves the wavefunction overlaps between the surface Dirac fermions of the undoped Bi$_2$Se$_3$ layer and those of the $d$-electrons in Cr-doped Bi$_2$Se$_3$ layer\cite{18,22–24}.

Concerning the temperature dependence of $J_{\text{eff}}$, we expect $J_{\text{SD}}$ to dominate at low $T$ because of the strong confinement of Dirac fermions to the surface layer and therefore negligible RKKY interaction between surface Dirac fermions and bulk $d$-electrons. On the other hand, $J_{\text{SD}}$ is sensitive to 3D long-range order of magnetic moments and so should diminish significantly above $T_c^{2D}$. In contrast, finite temperature can enhance wavefunction overlaps between the surface Dirac fermions and the interfacial $d$-electrons. Therefore, we expect $J_{\text{2D}}$ to dominate at elevated temperatures, and have further elaborated our rationale for this temperature dependence in supplementary information. Moreover, the long Fermi wavelength of surface Dirac fermions could result in much enhanced RKKY interaction in the bilayer system so that $J_{\text{2D}} > J_{\text{SD}}$\cite{18,22–24}, which may account for the empirical observation of $T_c^{2D} \gg T_c^{3D}$.

4.2. The magnitude and temperature dependence of the surface gap

Based on the scenario described above and noting that the proximity-induced surface gap is given by $\Delta = \langle J_{\text{eff}} \rangle M$ where $M$ is the surface magnetization that increases monotonically below $T_c^{2D}$, we find that with decreasing $T$, the surface gap $\Delta (T < T_c^{2D})$ can indeed exhibit a non-monotonic $T$-dependence that is consistent with our experimental findings depicted in figure 4. As qualitatively exemplified in supplementary figure 3, $\Delta (T)$ first increases with decreasing $T$ for $T < T_c^{2D}$, and then exhibits a ‘dip’ at $T_s$ where $T_c^{2D} > T_s > T_c^{3D}$, and $T_s$ represents a dimensional crossover temperature below which $J_{\text{SD}}$ becomes negligible. While we do not have sufficient information to model $\Delta (T)$ quantitatively, the qualitative agreement of
supplementary figure 3 with experimental results in figure 4 suggests that our proposed scenario for proximity magnetism in the bilayer system may provide useful guide for future investigation.

Next, we comment on the magnitude of the proximity-induced surface gaps in Bi$_2$Se$_3$, which were found to be comparable or even larger than the bulk gap ($\sim$0.3 eV) of Bi$_2$Se$_3$. While one may question whether it is feasible for a magnetism-induced surface gap to exceed its bulk gap of a TI, we point out that the bulk gap $\sim$0.3 eV of Bi$_2$Se$_3$ is an indirect gap; the direct gap at the $\Gamma$-point where the Dirac cone resides is in fact $>$0.5 eV based on bandstructure calculations [37]. In this context, the largest mean gap values (0.4 eV $\sim$ 0.5 eV) found in our work are well within the range of the bulk gap. We further note that the gap values determined from STS studies would be dominated by the local gap of the surface layer, whereas the gap value determined from ARPES would be sensitive to the smallest gap over an extended surface area. Therefore, the surface gap determined from STS tends to be larger than that determined from ARPES for an inhomogeneous sample. Indeed, ARPES studies on Bi$_{1-x}$Cr$_x$Se$_3$ have revealed a surface gap of $\sim$0.2 eV [18], which is slightly smaller than but still in reasonable agreement with our finding of $\Delta = (0.25 \pm 0.09)$ eV for a (1 + 6)-10% sample at $H = 0$ and $T = 79$ K, as shown in figure 4(b).

4.3. The feasibility of a much higher surface $T_c^{2D}$ than the bulk $T_c^{3D}$

Concerning the physical feasibility of a relatively high $T_c^{2D}$, we note that the energy splitting of the double-peak spectrum associated with isolated magnetic impurities in the surface state is comparable to the effective ferromagnetic coupling constant $J_{eff}$ [21]. Noting that the mean-field Curie temperature may be estimated from $J_{eff}$ via the relation $k_B T_c^{2D} \sim S(S + 1)(J_{eff}/3)$ [38] and that $J_{eff} \sim 0.1$ eV as determined from the measured energy splitting of the double resonances, we obtain $T_c^{2D} \sim 250$ K by assuming $S = 1/2$. While this rough estimate does not include the screening effect from Dirac fermions, it is still comparable to our STS measurements of $T_c^{2D} \sim 240$ K for $x = 10\%$ and $T_c^{2D} \sim 210$ K for $x = 5\%$ for the observed surface ferromagnetism, and is much higher than the bulk $T_c^{3D} \sim 25$ K. The disparity of $T_c^{2D}$ and $T_c^{3D}$ may be attributed to the different microscopic mechanisms for mediating ferromagnetism via the surface-state Dirac fermions versus the bulk-state carriers, particularly given the diverging Fermi wavelength of the Dirac fermions when the Fermi energy approaches the Dirac point [18, 22–24]. While quantitative details of the microscopic mechanism responsible for $T_c^{2D} > T_c^{3D}$ require further investigation, the relatively high $T_c^{2D}$ values are promising for realistic spintronic applications, particularly if our findings may be generalized to more homogeneously Cr-doped 3D-TIs such as (Bi$_{1-x}$Cr$_x$)$_2$Te$_3$ [18].

4.4. Topological spin textures

The appearance of both single- and double-peak magnetic impurity resonances is suggestive of two types of topological defects associated with an isolated magnetic impurity: The single-peak resonance may be attributed to a helical Dirac spin texture coupling to a magnetic moment pointing along the $c$-axis, whereas the double-peak resonance is associated with two opposite chiral spin textures of Dirac fermions coupling to an in-plane magnetic moment [21], as illustrated in figure 6(e). Our assignment of the single-peak resonances in this work to the helical Dirac spin texture coupled with isolated $c$-axis magnetic moments can be justified by their strong and non-monotonic temperature dependence near $T_c^{2D}$ (figure 6(f)), and also by their suppression under large $c$-axis magnetic fields. In contrast, our previous studies of non-magnetic impurity resonances in pure Bi$_2$Se$_3$ MBE-grown thin films [32] did not find any dependence of their occurrences on either the temperature or the applied magnetic field, implying that the physical origin of the single-peak resonances in pure Bi$_2$Se$_3$ is fundamentally different from that of the single-peak resonances observed in the bilayer systems.

Our finding of occurrences of impurity resonances only along the borders of gapped and gapless regions is consistent with suppressed long-range magnetic order along the boundaries between the $c$-axis oriented (gapped) and in-plane oriented (gapless) magnetic domains [31]. Thus, proximity-induced magnetization in the top Bi$_2$Se$_3$ layer is also much suppressed for regions above the boundaries of $c$-axis and in-plane magnetic domains [31], and Cr-ions located in these regions were more likely to decouple from long-range magnetization and became effectively isolated magnetic impurities, particularly with the assistance of thermal fluctuations at sufficiently high temperatures (figure 6(f)).

Finally, we note that the spin textures associated with an in-plane magnetic impurity may be considered as a stable ‘topological bit’ with two levels associated with the two opposite spin chirality. In principle, for a completely isolated topological bit, the two-level states may be tuned by a local $c$-axis magnetic field. Further, for $E_F \rightarrow E_D$ these topological bits are long-lived as the result of topological protection. On the other hand, tuning $E_F$ away from $E_D$ will result in increasing coupling among spatially separated topological bits [21], which may be viewed as inducing an effective entanglement of wavefunctions among these topological bits. The feasibility of tuning the two levels within a topological bit by an external magnetic field and the coupling among spatially
separated bits by gating the Fermi level may present an interesting opportunity for applying these topological bits to quantum information technology.

5. Conclusion

We have demonstrated STS evidences for magnetism-induced massive Dirac spectra and topological defects in the surface state of MBE-grown 3D-TIs that consisted of bilayers of undoped Bi$_2$Se$_3$ on top of Cr-doped Bi$_2$Se$_3$. For an undoped layer thinner than or equal to 3-QL, proximity-induced ferromagnetism was manifested by the appearance of a surface gap $\Delta$ below a transition temperature $T_c^{\text{3D}} > 200$ K, and the value of $T_c^{\text{3D}}$ was found to be Cr-doping $(x)$ dependent and also much higher than the bulk ferromagnetic transition temperature $T_c^{\text{2D}} (<30 \text{ K})$. Our finding of $T_c^{\text{3D}} > T_c^{\text{3D}}$ may be attributed to the much longer range of the RKKY interaction mediated by the surface Dirac fermions relative to that mediated by the bulk itinerant carriers. The gap distribution was spatially inhomogeneous, and its average value and spatial homogeneity at low $T$ increased with $H$ and $x$, confirming its magnetic origin. On the other hand, the non-monotonic $T$-dependence of $\Delta$ may be attributed to proximity magnetism induced by two types of contributions: a 3D contribution from the bulk magnetism that dominates at low $T$, and a 2D contribution associated with the RKKY interactions mediated by surface Dirac fermions, which dominates at $T_c^{\text{3D}} \ll T < T_c^{\text{2D}}$. The appearance of an energy gap below $T_c^{\text{3D}}$ is the result of global time-reversal symmetry breaking in the surface state of topological insulators. This global effect is in contrast to the local time-reversal symmetry breaking associated with isolated magnetic impurities in the surface state, which tend to induce excess densities of states near the Dirac point. Finally, topological defects associated with helical spin textures of Dirac fermions around isolated magnetic impurities were manifested as long-lived sharp double-peak spectral resonances along the borders of gapped and gapless regions. The strong spatial localization and long life-time of these magnetic impurity resonances represent interesting topological bits that are potentially useful for applications to quantum information technology.

Acknowledgments

The work at Caltech was jointly supported by the Defense Advanced Research Projects Agency (DARPA), Focus Center Research Program: Center on Functional Engineered Nano Architectonics (FENA), and by the National Science Foundation (NSF), Physics Frontier Center: Institute for Quantum Information and Matter (IQIM). The work at UCLA was supported by DARPA/FENA. We thank Professors Gabriel Aeppli, Alexei Kitaev, Nai-Phaun Ong and Thomas Rosenbaum for useful discussions.

References

[35] Zhang Y et al 2010 Nat. Phys. 6 581
[37] Zhang H et al 2009 Nat. Phys. 5 438
[38] Kittel C 2004 Introduction to Solid State Physics 8th edn (Oxford: Wiley)